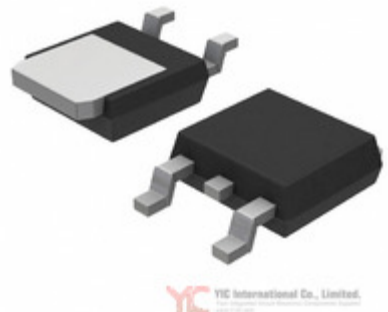

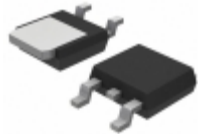
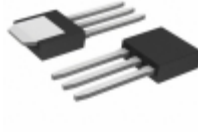

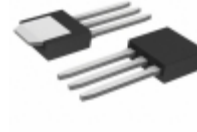
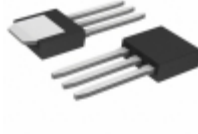
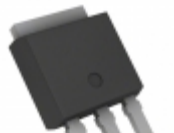
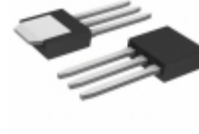
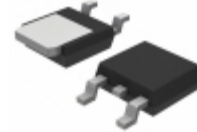
	<p>Hersteller-Teilenummer: NTD32N06T4G</p>
	<p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p>
	<p>Teil der Beschreibung: MOSFET N-CH 60V 32A DPAK</p>
	<p>Datenblätter:  NTD32N06T4G.pdf</p>
	<p>RoHs Status: Bleifrei / RoHS-konform</p>
	<p>Lagerzustand: New original, 5010 pcs Stock Available.</p>
	<p>Liefern von: Hong Kong</p>
	<p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTD32N06T4G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 32A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	5010 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (Tj)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	1.5W (Ta), 93.75W (Tj)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	32A (Ta)
Rds On (Max) @ Id, Vgs	26 mOhm @ 16A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	60nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1725pF @ 25V
Verpackung	Tape & Reel (TR)



















































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Sie können auch interessiert sein:

 <p>NTD32N06LT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 32A DPAK</p>	 <p>NTD32N06L-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 32A IPAK</p>	 <p>NTD32N06LT4 AMI Semiconductor / ON Semiconductor NTD32N06LT4 ON/</p>	 <p>NTD32N06L-001 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 32A IPAK</p>
 <p>NTD3808N-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 16V 12A IPAK</p>	 <p>NTD3813N-35G AMI Semiconductor / ON Semiconductor MOSFET N-CH 16V 9.6A IPAK</p>	 <p>NTD3813N-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 16V 9.6A IPAK</p>	 <p>NTD32N06LG AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 32A DPAK</p>

heiße Teile

Mehr

 NTD3055L104	 NTD3055L104-1G	 NTD3055L104G	 NTD3055L104T4G	 NTD3055L170
 NTD3055L170-001	 NTD3055L170-1G	 NTD3055L170G	 NTD3055L170T4	 NTD3055L170T4G
 NTD3055LT4G	 NTD3055VLT4G	 NTD30N02G	 NTD30N02T4	 NTD30N02T4G
 NTD30N06RT4	 NTD30N06T4G	 NTD32N06-001	 NTD32N06-1G	 NTD32N06G
 NTD32N06L	 NTD32N06L-001	 NTD32N06L-1G	 NTD32N06LG	 NTD32N06LT4G
 NTD3808NT4G	 NTD3813NT4G	 NTD3817NT4G	 NTD40N03R	 NTD40N03R-1
 NTD40N03R-1G	 NTD40N03RG	 NTD40N03RT4	 NTD40N03RT4G	 NTD4302-001
 NTD4302-001G	 NTD4302-1G	 NTD4302G	 NTD4302T4	 NTD4302T4G
 NTD4804N	 NTD4804NT4G	 NTD4805N	 NTD4805N-1G	 NTD4805NT4G
 NTD4806N	 NTD4806N-35G	 NTD4806NA-35G	 NTD4806NG	 NTD4806NT4G

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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